NORTH MAHARASHTRA UNIVERSITY, JALGAON

SYLLABUS FOR F.Y.B.Sc. (WITH EFFECT FROM JUNE 1992)

ELECTRONICS

Approved svllabi of F.Y.B.Sc. ÷--

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PAPER - I SECTION A (FIRST TERM)

Passive Electronic components and network the eorems.

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<u>RESISTORS</u> :- Symbol, colour code, types such as carbon, 1] metal-film, thin-film,wire-wound, variable resisters (Logarithmic and linear potentiometer and presets) (06 periods)

- CAPACITORS : Symbol, colour-code, types such as paper, 2] mica, tantalum, polystyrene, electrolytic, variable capacitors (gang and trimmer). (06 periods)
- INDUCTORS :- Symbol, types such as air core, iron-core, 3] frrite core, chokes. (05 periods)

The study of above passive components should be as regards to

- **i**) composition/construction/design
- ii) range values
- iii) practical limitations
- iv) electrical properties
- parameters/ ratings / specifations additional information. v)
- vì)
- vii) fields of applications.
- <u>SWITCHES</u> :- Idea of SPDT, DPDT switches, Types such as toggle switch, rotary switch, relay as a switch 4] (electromagnetic) (Ø2 periods)
- 5] :- Tunned circuits (series and parallel NETWORKS resonant), coupled circuits (transformer coupled and doubly tunned), passive filters (low pass, high pass, band pass using R.L. and C.elements) (09 periods)
- 63 NTIWORK - THEOREMS :- Kirchhoff's current and voltage laws. Thevenin's theorem, Norton's theorem, maximum power transfer theorem, superpostion theorem. (8 Periods)

REFERENCE BOOKS

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1.	Understanding of electrinic components	;	Walter
2.	Electronic principles	;	V.K. Mehta
З.	Basic electronics	:	B. Grob.
4.	Basic Electronics	:	D.C. Tayal
5.	Networks, lines & fields	:	J.D.Ryder (4th edn)
6.	Electronic fundamentals and applications	;:	J.D. Ryder
7.	A monograph integrated electronics & circuits	:	Ketan & Goyal \
8.	Circuit Elements	;	Philips Publication

PAPER - I SECTION B (SECOUND TERM) : DIGITAL ELECTRONICS

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NUMBER SYSTEMS :- Decimal, Binary, Octal, Hexadecimal number systems, BCD code, Intercoversion of decimal, binary and hex numbers. (06 Periods)

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- 2] LOGIC GATES :- Positive and Negative logic, OR, AND, NOT, NDR, NAND and EX-OR gates, Study of 7400,7402,7404.7408IC's [internal logic diagrams & pin connections] Diode logic, DTL, TTL and Emitter coupled logic, Basic building blocks of TTL, gates. Multtiemeter input transistor invertor, Totempole and open collector outputs (10 Periods)
- 3] BINARY ARITHMATIC AND BOOLEAN ALGEBRA :- Binary addition and subtraction,1's complement,2's complement, Half and full-adders, Boolean axioms, D'Morgans theorems (statement, verification and application). (10 Periods)
- 4] <u>FLIP-FLOPS</u> :- R-S, clocked R-S J-K, Master slave J-K, D and T flip-flop (using logic gates). (06 Periods)
- 5] <u>COUNTERS</u> :- 4-bit binary counter, Decade counter, BCD counter. (Ø4 Periods)

REFERENCE - BOOKS

- 1. Digital principles & applications : Malvino & Leach
- Digital Electronics
 Digital Electronics
 Gothman
 Digital Electronics
 V.K. Jain
 Digital Computer Electronics
 A.P. Malvino

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PAPER - II SECTION A(FIRST TERM) : SEMICONDUCTOR DEVICES

- SEMICONDUCTORS :- Review of atomic structure, Formation of energy bands, Energy diagrams for conductors, Semiconductors and insulators, Charge carriers in semiconductors (Electron-hole pair), Intrinisc and Extrinsic semiconductors, Doping (P and N type semiconductors). (08 Periods)
- 2] <u>P-N JUNCTION</u> :- Junction diode. Depletion layer and barrier potential. Effect of forward and reverse bias on depletion layer and barrier potential. I-V characteristics. Junction diode as a switch: and as a rectifier, Study of Zener diode, varactor diode, photodiode. LED (Symbol, biasing and applications). (06 Periods)
- 3] BIPOLAR JUNCTION TRANSISTOR (BJT) :-

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Frinciple of operation, CB, CE and CC configurations, Input, Output and Transfer characteristics for CE configuration, Relation between alpha and beta. (Ø4 Periods)

- 4] <u>UNI-JUNCTION TRANSISTOR (VJT)</u> :- Basic working principle Characteristics and use as a switch and relaxation osillator. (Ø4 Periods)
- 5] <u>FIELD EFECT TRANSISTOR (FET)</u> :- Basic working principle, characteristics, Pinch-off Voltage, use of FET as VVR, depletion and enhancement type MOS-FETs. (05 Periods)
- 6] <u>SILICON CONTROLLED RECTIFIER (SCR)</u> :- Four-layer diode, Characteristics. Use of SCR as a switch, Triac.

(04 periods)

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REFERENCE BOOKS

1.	SODID-STATE DEVICES	: Taper (Vol. I)	
2.	BASIC ELECTRONICS	: D.C. Tayal	
З.	BASIC ELECTRONICS FOR SCIENTISTS	: Jamesh J. Brophy	
4.	ELECTRONIC PRINCIPLES	: V.K. Metha	
5.	BASIC ELECTRONICS	: E. Grob	÷
6.	ELECTRONIC PRINCIPLES	: A.P. Malvino	
7.	SEMICONDUCTOR DEVICES	: Millman and Halkias	

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PAPER - II SECTION B (SECOUND TERM) : BASIC ELECTRONIC CIRCUITS

- 1] RECTIFIER CIRCUITS :- Half wave, Full wave and bridge rectifier circuits, capacitive filter, LC filters (capacitor input, choke input and II filters), ripple factor, voltage doubler.
- 2] TRANSISTOR BLASING METHODS :- Fixed bias, Collector to base bias, and self-bias circuit. (Ø4 Periods)
- 3] <u>AMPLIFIER CIRCUITS</u> :- single stage R-C coupled CE amplifier, AC & DC Load line, Operating point Thermal runaway, class A, class B and Class c amliifiers, crossover distrotion, push-pull amplifier. (Ø6 Periods)
- 4] <u>OSCILLATOR AND MULTIVIBRATOR CIRCUITS</u> :- Positive and negative feedback, Effects of negative feedback, Barkhausen critería, Phase-shift oscillator, Astable, monostable and bistable multivibrators (transistorised).
- 5] <u>DIFFERENTIAL AMPLIFIER CIRCUITS</u> :- Black-box concept, common mode and idfferential mode, CMRR, Analysis of single ended and differential input (Ø3 Periods)
- 6] OPERATIONAL AMPLIFIER CIRCUITS (OP-AMP):-Symbol, Ideal

Characterstics, Inverting and Noninverting configurations, Virtual ground, Ic 741 pin connections (DIP and TO packages) and characteristics.OP-AMP as an adder,subtractor, differentiator and integrator. ' (Ø6. periods).

REFERENCE - BOOKS :

- 1. Electronics principles A.P.Malvino
- 2. Integrated Electronics-MILLMAN & HALKIAS
- 3. OP-AMP G.B.CLYTON
- 4. Pulse, Digital & Switching waveforms Millmen & taub
- 5. Solid state Devices Taper (volume I1)
- Electronics Devices and circuits-Allen Mottershed.

PRACTICALS:

PAPER - III (FIRST TERM)

- Demonstration of electrical and electronic components **i**) R.L.C.transformer, choke, switches, relay, diode.BJT, UJT, FET etc. (Nomenclature types, ratings, etc.)
- ii) Use of analog and digital multimeters (measurements of R,voltage and current).
- Use of Signal generator/function generator . 111) (measurement of o/p frequency/amplitude)
 - Use of CRC (measurement of freq./period and amplitude) Use of power-supply (Dual,fixed,variable and current iv) v) limit)
 - study of series and parallel resonance circuits. 1]

R-L filters and R.C.filters (low, high and band pass) 2] Verfication of Thevenin and Norton theorems and 3] Maximum power transfer theorem.

- P-N junction characteristics. BJT characteristics. 43
- 51)
- UJT characteristics. 6 J
- FET characteristics. 7)
- 8] SCR characteristics.

The above five exercises/experimetn (i) to (v) should be regarded as prerequisite.

Paper-III (Second TErm) :--

- 1] A)OR and AND gates using Diode logic and B)Study of logic gates (OF, AND, NOT, NAND, NOR) using various ICs (truth table verification)
- 21Half-adder, full-adder circuits
- 31 verification of D'Morgan's theorems.
- Study of flip-flops using various ICs. 4]
- Study of rectifier circuits with filters, 5]
- calculations of ripple-factor.
- Single stage R-C coupled amplifier (with and without-6] ve feedback) 71
- A stable multivibrator (Transistorised)
- OP-AMP (741) parameters (o/p adm i/p impendance 81 measurement)

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